

SN5440, SN54LS40, SN54S40, SN7440, SN74LS40, SN74S40

Dual 4-Input Positive-NAND Buffers

These devices contain two independent 4-input NAND buffer gates. The SN5440, SN54LS40, and SN54S40 are characterized for operation over the full military temperature range of -55°C to 125°C while the SN7440, SN74LS40, and SN74S40 are characterized for operation from 0°C to 70°C.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

SN5440, SN54LS40, SN54S40, SN7440, SN74LS40, SN74S40 DUAL 4-INPUT POSITIVE-NAND BUFFERS

APRIL 1985—REVISED MARCH 1988

- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers and Flat Packages in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability

description

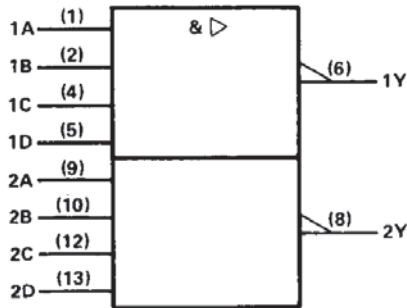
These devices contain two independent 4-input NAND buffer gates.

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FUNCTION TABLE (each gate)

INPUTS				OUTPUT
A	B	C	D	Y
H	H	H	H	L
L	X	X	X	H
X	L	X	X	H
X	X	L	X	H
X	X	X	L	H

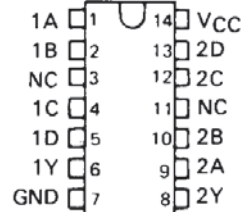
logic symbol†



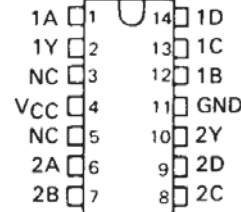
†This symbol is in accordance with ANSI/IEEE Std. 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, N, and W packages.

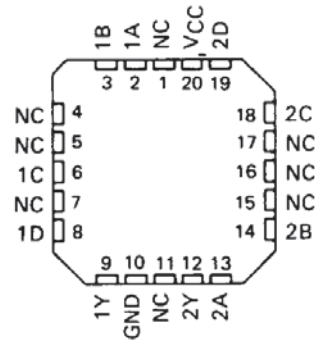
SN5440 . . . J PACKAGE
SN54LS40, SN54S40 . . . J OR W PACKAGE
SN7440 . . . N PACKAGE
SN74LS40, SN74S40 . . . D OR N PACKAGE
(TOP VIEW)



SN5440 . . . W PACKAGE
(TOP VIEW)

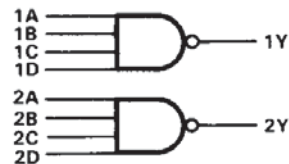


SN54LS40, SN54S40 . . . FK PACKAGE
(TOP VIEW)



NC - No internal connection

logic diagram



positive logic

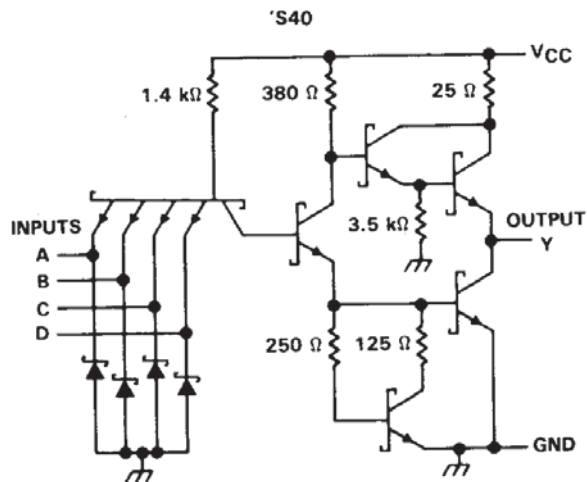
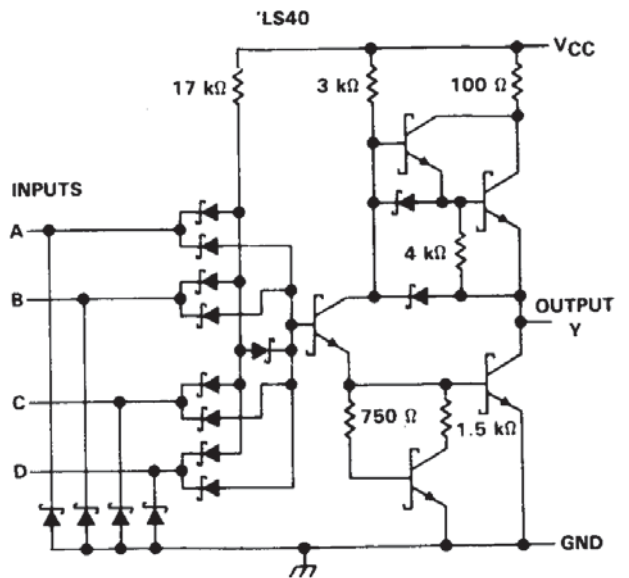
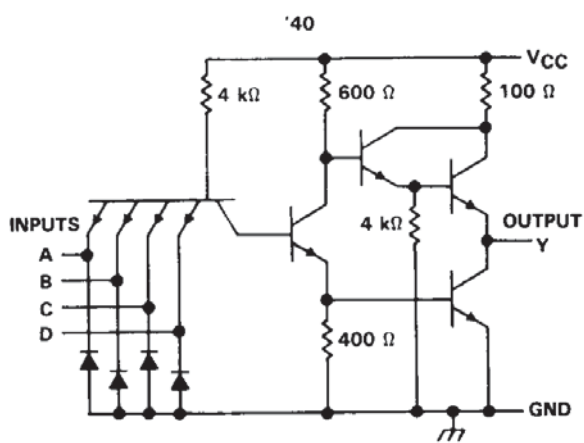
$$Y = A \cdot B \cdot C \cdot D \text{ or } Y = \bar{A} + \bar{B} + \bar{C} + \bar{D}$$

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TTL Devices

**SN5440, SN54LS40, SN54S40,
SN7440, SN74LS40, SN74S40
DUAL 4-INPUT POSITIVE-NAND BUFFERS**

schematics (each gate)



Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1)	7 V
Input voltage: '40, 'S40	5.5 V
'LS40	7 V
Operating free-air temperature range: SN54'	-55°C to 125°C
SN74'	0°C to 70°C
Storage temperature range	-65°C to 150°C

NOTE 1: Voltage values are with respect to network ground terminal.

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TTL Devices

SN5440, SN7440 DUAL 4-INPUT POSITIVE-NAND BUFFERS

recommended operating conditions

	SN5440			SN7440			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH} High-level input voltage	2			2			V
V_{IL} Low-level input voltage			0.8			0.8	V
I_{OH} High-level output current			-1.2			-1.2	mA
I_{OL} Low-level output current			48			48	mA
T_A Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN5440			SN7440			UNIT
		MIN	TYP ‡	MAX	MIN	TYP ‡	MAX	
V_{IK}	$V_{CC} = \text{MIN}, I_I = -12 \text{ mA}$			-1.5			-1.5	V
V_{OH}	$V_{CC} = \text{MIN}, V_{IL} = 0.8 \text{ V}, I_{OH} = -1.2 \text{ mA}$	2.4	3.3		2.4	3.3		V
V_{OL}	$V_{CC} = \text{MIN}, V_{IH} = 2 \text{ V}, I_{OL} = 48 \text{ mA}$		0.2	0.4		0.2	0.4	V
I_I	$V_{CC} = \text{MAX}, V_I = 5.5 \text{ V}$			1			1	mA
I_{IH}	$V_{CC} = \text{MAX}, V_I = 2.4 \text{ V}$			40			40	μA
I_{IL}	$V_{CC} = \text{MAX}, V_I = 0.4 \text{ V}$			-1.6			-1.6	mA
$I_{OS} §$	$V_{CC} = \text{MAX}$	-20		-70	-18		-70	mA
I_{CCH}	$V_{CC} = \text{MAX}, V_I = 0$		4	8		4	8	mA
I_{CCL}	$V_{CC} = \text{MAX}, V_I = 4.5 \text{ V}$		17	27		17	27	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at $V_{CC} = 5 \text{ V}, T_A = 25^\circ\text{C}$.

§ Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed 100 milliseconds.

switching characteristics, $V_{CC} = 5 \text{ V}, T_A = 25^\circ\text{C}$ (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	Any	Y	$R_L = 133 \Omega, C_L = 15 \text{ pF}$		13	22	ns
t_{PHL}					8	15	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

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TTL Devices

SN54LS40, SN74LS40 DUAL 4-INPUT POSITIVE-NAND BUFFERS

recommended operating conditions

	SN54LS40			SN74LS40			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH} High-level input voltage	2			2			V
V _{IL} Low-level input voltage			0.7			0.8	V
I _{OH} High-level output current			-1.2			-1.2	mA
I _{OL} Low-level output current			12			24	mA
T _A Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN54LS40		SN74LS40		UNIT		
		MIN	TYP ‡	MAX	MIN		TYP ‡	MAX
V _{IK}	V _{CC} = MIN, I _I = -18 mA			-1.5		-1.5	V	
V _{OH}	V _{CC} = MIN, V _{IL} = MAX, I _{OH} = -1.2 mA	2.5	3.4		2.7	3.4	V	
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 12 mA		0.25	0.4		0.25	0.4	V
	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 24 mA					0.35	0.5	V
I _I	V _{CC} = MAX, V _I = 7 V			0.1		0.1	mA	
I _{IH}	V _{CC} = MAX, V _I = 2.7 V			20		20	μA	
I _{IL}	V _{CC} = MAX, V _I = 0.4 V			-0.4		-0.4	mA	
I _{OS} §	V _{CC} = MAX	-30		-130	-30	-130	mA	
I _{CCH}	V _{CC} = MAX, V _I = 0		0.45	1		0.45	1	mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V		3	6		3	6	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Any	Y	R _L = 667 Ω, C _L = 45 pF		12	24	ns
t _{PHL}					12	24	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

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TTL Devices

SN54S40, SN74S40

DUAL 4-INPUT POSITIVE-NAND BUFFERS

recommended operating conditions

	SN54S40			SN74S40			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH} High-level input voltage	2			2			V
V _{IL} Low-level input voltage			0.8			0.8	V
I _{OH} High-level output current			-3			-3	mA
I _{OL} Low-level output current			60			60	mA
T _A Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN54S40		SN74S40		UNIT		
		MIN	TYP ‡	MAX	MIN		TYP ‡	MAX
V _{IK}	V _{CC} = MIN, I _I = -18 mA			-1.2		-1.2	V	
V _{OH}	V _{CC} = MIN, V _{IL} = 0.8 V, I _{OH} = -3 mA	2.5	3.4		2.7	3.4	V	
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 60 mA			0.5		0.5	V	
I _I	V _{CC} = MAX, V _I = 5.5 V			1		1	mA	
I _{IH}	V _{CC} = MAX, V _I = 2.7 V			0.1		0.1	mA	
I _{IL}	V _{CC} = MAX, V _I = 0.5 V			-4		-4	mA	
I _{OS} §	V _{CC} = MAX	-50		-225	-50	-225	mA	
I _{CCH}	V _{CC} = MAX, V _I = 0		10	18		10	18	mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V		25	44		25	44	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed 100 milliseconds.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Any	Y	R _L = 93 Ω, C _L = 50 pF	4	6.5		ns
t _{PHL}				4	6.5		ns
t _{PLH}			R _L = 93 Ω, C _L = 150 pF	6			ns
t _{PHL}				6			ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

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TTL Devices